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AW	บร	3,652,956		1972-03-28	Pinnow et al.			 	
2W	US	4,314,910	 	1982-02-09	Barnes	 		 	· · ·
9w	US	5,006,908		1991-04-09	Matsuoka et al.				
AW.	US	5,369,289	<u> </u>	1994-11-29	Tamaki et al.				
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âW	JP	59-30107	U	1984-02-24	JAPAN			YES	NO X
ON V	JP	7-32638	U	1995-06-16	JAPAN	-		x	
	JP	01-257993	A	1989-10-16	JAPAN			ABS	
OW.	JP	01-260707	A	1989-10-18	JAPAN			ABS	
	JР	02-111922	A	1990-04-24	JAPAN			ABS	
aw aw	JР	05-142424	- A	1993-06-11	JAPAN				
	JP	06-160635	A	1994-06-07	JAPAN			X	
XX	JР	06-027327	A	1994-08-07			 7	Х	
W W	JP	06-82633	A		JAPAN			X	
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OTHER	TEL, SAMPOSI	um, catalog, etc., date,	paye(s), voi	ume-issue number(s), publi	itle of the article (when appropriate, city and/or country where p	ublished.			megasine,
SW	"White Shimbu	LED lamp: Eff n, September 1	icient : 3, 1996	light-emitting; , Published by N	Manufacture cost ha Wihon Keizai Shimbur	lf", N sha.	Vikkei S	Sangyo	
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dw	Vol. 3	NAKAMURA et al 2 (1993), pp.	., "Si-I L16-L19,	Ooped InGaN Film , Part 2, No. 14	ns Grown on GaN Film A/B, 15 January 1993	ns", Jr 	on. J. A	Appl. 1	Phys.
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V.V	Emitting Diodes", Jpn. J. Appl. Phys. Vol. 32 (1993), pp. L8-L11, Part 2, No. 1A/B, 15, January 1993.								
dw	Shuji NAKAMURA, "Zn-doped InGaN growth and InGaN/AlGaN double-heterostructure blue-light-emitting diodes", Journal of Crystal Growth, 145 (1994), pp. 911-917.								
gn	Shuji Diodes	NAKAMURA, "High ", IEDM 94 (199	n-Power 94), IEB	InGaN/AlGaN Dou EE, pp. 567-570.	no month			Emitti:	ng
dw	Kozo O Journa	SAMURA et al., l of Applied Pl	"Prepar nysics,	ration and optic Vol. 46, No. 8,	al properties of Ga August 1975, pp. 3	1 _{1-x} In _x N 432-34	thin f	ilms",	
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AW.	JP	07-114904	A	1995-05-02	JAPAN			х	
an	JP	07-235207	A	1995-09-05	JAPAN			Х	
AN	JP	53-7153		1978-01-21	JAPAN				Х
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2h/	JP	55-4898	A	1980-01-14	JAPAN				х
2W	JP	55-005533	A	1980-01-16	JAPAN			ABS	
AW	JP	60-185457	A	1985-09-20	JAPAN	_		ABS	
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AW	Takash	i MATSUOKA et	al., "G	rowth and Prope	rties of a Wide-Gap Vol. 5, No. 1, pp.	Semico	onductor June 199	InGal	J" ,
AW	T. NAG 1993,	ATOMO et al., Vol. 93-10, pp	"Ga _{1-x} In _x . 136-14	N Blue Light-En	nitting Diodes", Pr L	oc. Ele	ctroche	m. Soc	.,
AW/	G. BLASSE et al., "Investigation of Some Ce ^{3*} -Activated Phosphors", Journal of Chemical Physics, Vol. 47, No. 12, 15 December 1967.								
JW/	W.W. HOLLOWAY, Jr. et al., "On The Fluorescence of Cerium - Activated Garnet Crystals", Physics Letters, Vol. 25A, No. 8, 23 October 1967, pp. 614-615.								
	E.F. G. Y ₃ Al ₅ O ₁₂	IBBONS et al., :Ce ^{3.} ", J. Elec	"Some I	Factors Influent 1. Soc., Vol. 12	cing the Luminous I		naractei NO MON		of
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gw	JP	07-120754	A	1995-05-12	JAPAN			х	
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AN	JP	05-63068	Ü	1993-08-20	JAPAN	_	_	Х	
AW .	EP	0 209 942	A1	1987-01-28	EPO				
Jan Jan	EP	0 541 373	A2	1992-11-05	EPO				
HW.	EP	0 599 224	A1	1994-06-01	EPO		<u> </u>		
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	Vol. 1	<u>AN et al., "Pr</u> 34, No. 2.	eparatio	on of Y3Al5O12-Ba	ased Phosphor Powde	ers, J.	Electro	chem.	Soc.,
Sw	Report	, translation	of page	sample shipmen 15 of Nikkei E	t of white light e lectronics 1996.9.	23 (No.	671).		
	"Proce	edings of the	Institut	e of Phosphor	Society", Translat F Phosphor Society	ion of p	pages 1,	5 to	14
				·		nu	year.		
	Shigeo	SHIONOYA et a	1. (edit	ors), "Phospho	r Handbook", pp. 5	05-508,	CRC Pi	cess.	
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AW	US	4,727,283		1988-02-23	van Kemenade et al	_			
W	US	4,298,820		1981-11-03	Bongers et al.				
AW	US	3,699,478		1972-10-17	Pinnow et al.				
AW	US	5,798,537		1998-08-25	Nitta				
WW	US	5,202,777		1993-04-13	Sluzky et al.				
W.	us	3,819,974		1974-06-25	Stevenson et al.				
2W	·US	5,847,507		1998-12-08	Butterworth et al.				
20/	US	3,691,482		1972-09-12	Pinnow et al.			 	
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	JР	01179471	A	1989-07-17	JAPAN	_		ABS	
	JP	5043913	C1	1975-04-21	JAPAN				
	JP	554898	A	1980-01-14	JAPAN				
	JР	09027642	A	1997-01-28	JAPAN			ABS	
	JP	08007614	A	1996-01-12	JAPAN			ABS	-
	JP	07176794	A	1995-07-14	JAPAN			ABS	
	JР	07099345	A	1995-04-11	JAPAN			ABS	
	JP	05152609	A	1993-06-18	JAPAN			ABS	
	JP	6220237	A	1987-01-28	JAPAN				
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	Glasse	et al., Appli	ed Phys:	ics Letters, Vo	1. 11, No. 2, pp. 53	3-54 (3	1967)		
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W/W/	JP	49112577		1974-10-26	JAPAN	_	_	ABS	
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AW	"Phosphors Based on Rare-Earths, A New Era in Fluorescent Lighting", B.M.J. Smets, Materials Chemistry and Physics, 16 pp. 283-299 (1987)								
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JW_	JP	10036835	A	1998-02-10	JAPAN			ABS	
$\mathcal{A}W_{\angle}$	JP	49106283		1972-12-27	JAPAN			ABS	
XW_	JP	5245181		1977-10-14	JAPAN			ABS	
aW	GB	1589964		1981-05-20	GREAT BRITAIN				
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WN/	JP	5331584		1978-03-24	JAPAN	_			
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JP 06177423	1994-06-2	4 JAPAN		ABS
JP 06260680	1994-09-1	6 JAPAN		ABS
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